

Silicon Carbide Schottky Diode

650 V, 30 A

FFSH3065ADN-F155

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 81 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb-Free, Halogen Free/BFR Free and RoHS Compliant

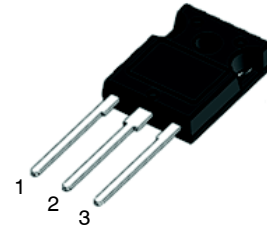
Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

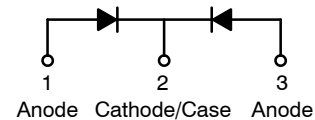


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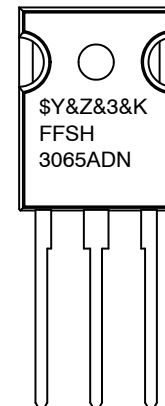
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TO-247
LONG LEAD
CASE 340CH



MARKING DIAGRAM



\$Y = ON Semiconductor Logo
&Z = Assembly Plant Code
&3 = Numeric Date Code
&K = Lot Code
FFSH3065ADN = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

FFSH3065ADN-F155

Table 1. ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		650	V
E_{AS}	Single Pulse Avalanche Energy (Note 1)		81	mJ
I_F	Continuous Rectified Forward Current @ $T_C < 148^\circ\text{C}$ (Note 2)		16*/30**	A
	Continuous Rectified Forward Current @ $T_C < 135^\circ\text{C}$		23*/36**	
$I_{F,Max}$	Non-Repetitive Peak Forward Surge Current	$T_C = 25^\circ\text{C}$, 10 μs	1000	A
		$T_C = 150^\circ\text{C}$, 10 μs	900	A
$I_{F,SM}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\text{ ms}$	90	A
$I_{F,RM}$	Repetitive Forward Surge Current	Half-Sine Pulse, $t_p = 8.3\text{ ms}$	50	A
P_{tot}	Power Dissipation	$T_C = 25^\circ\text{C}$	165	W
		$T_C = 150^\circ\text{C}$	28	W
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +175	$^\circ\text{C}$
	TO247 Mounting Torque, M3 Screw		60	Ncm

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 81 mJ is based on starting $T_J = 25^\circ\text{C}$, $L = 0.5\text{ mH}$, $I_{AS} = 18\text{ A}$, $V = 50\text{ V}$.

2. Limited by per device.

Table 2. THERMAL CHARACTERISTICS

Symbol	Parameter	Rating	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.91*/0.4**	$^\circ\text{C/W}$

* Per Leg

** Per Device

Table 3. OPERATING CHARACTERISTICS ($T_C = 25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_F	Forward Voltage	$I_F = 16\text{ A}$, $T_C = 25^\circ\text{C}$	–	1.5	1.75	V
		$I_F = 16\text{ A}$, $T_C = 125^\circ\text{C}$	–	1.6	2.0	
		$I_F = 16\text{ A}$, $T_C = 175^\circ\text{C}$	–	1.72	2.4	
I_R	Reverse Current	$V_R = 650\text{ V}$, $T_C = 25^\circ\text{C}$	–	–	200	μA
		$V_R = 650\text{ V}$, $T_C = 125^\circ\text{C}$	–	–	400	
		$V_R = 650\text{ V}$, $T_C = 175^\circ\text{C}$	–	–	600	
Q_C	Total Capacitive Charge	$V = 400\text{ V}$	–	52	–	nC
C	Total Capacitance	$V_R = 1\text{ V}$, $f = 100\text{ kHz}$	–	887	–	pF
		$V_R = 200\text{ V}$, $f = 100\text{ kHz}$	–	95	–	
		$V_R = 400\text{ V}$, $f = 100\text{ kHz}$	–	72	–	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PART MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSH3065ADN-F155	FFSH3065ADN	TO-247 Long Lead	Tube	N/A	N/A	30 units

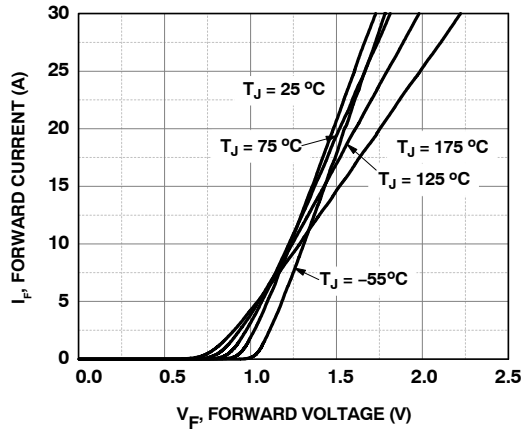
TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Figure 1. Forward Characteristics

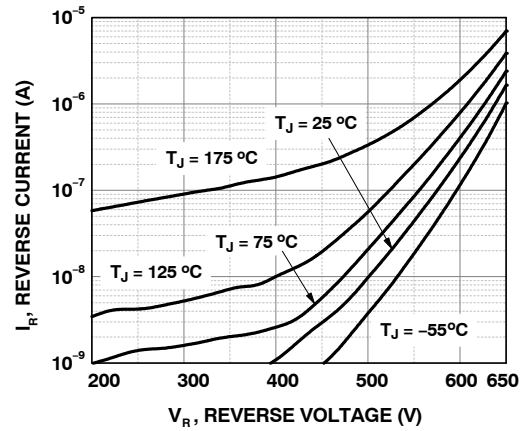


Figure 2. Reverse Characteristics

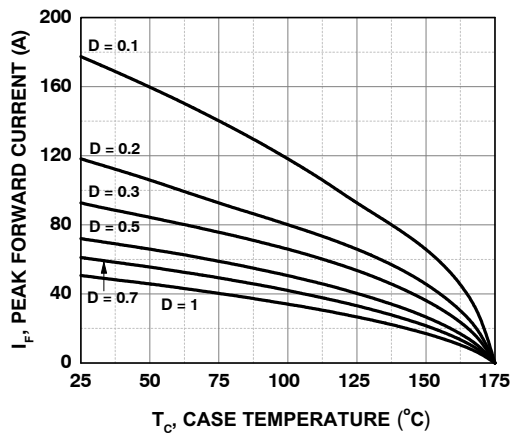


Figure 3. Current Derating

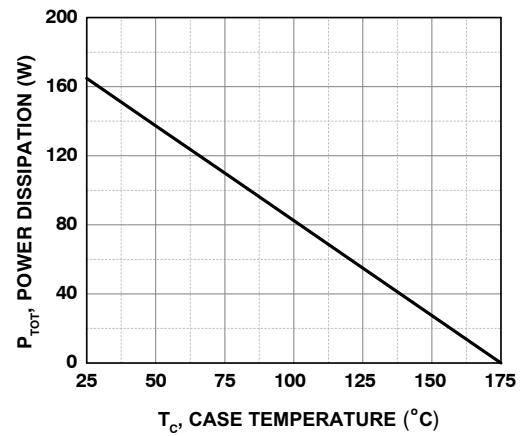


Figure 4. Power Derating

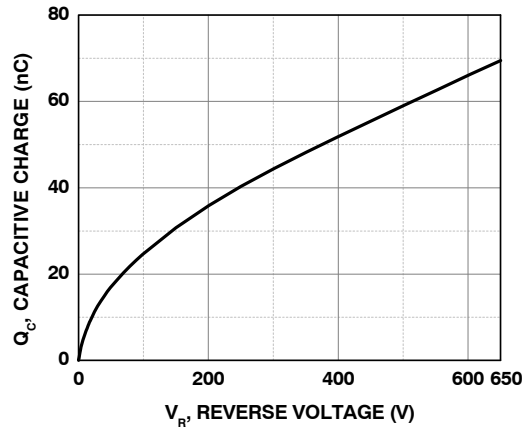
TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Figure 5. Capacitive Charge vs. Reverse Voltage

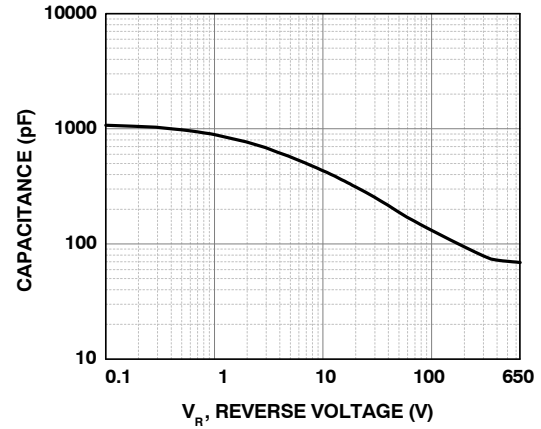


Figure 6. Capacitance vs. Reverse Voltage

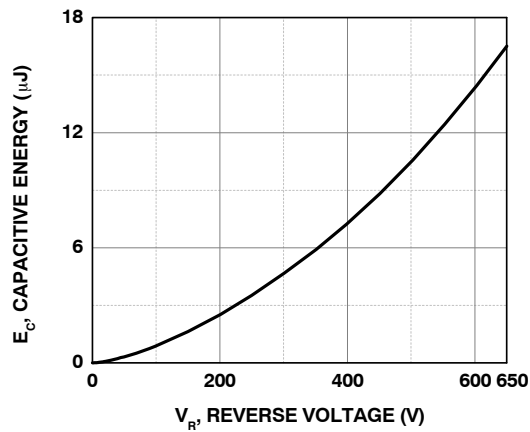


Figure 7. Capacitance Stored Energy

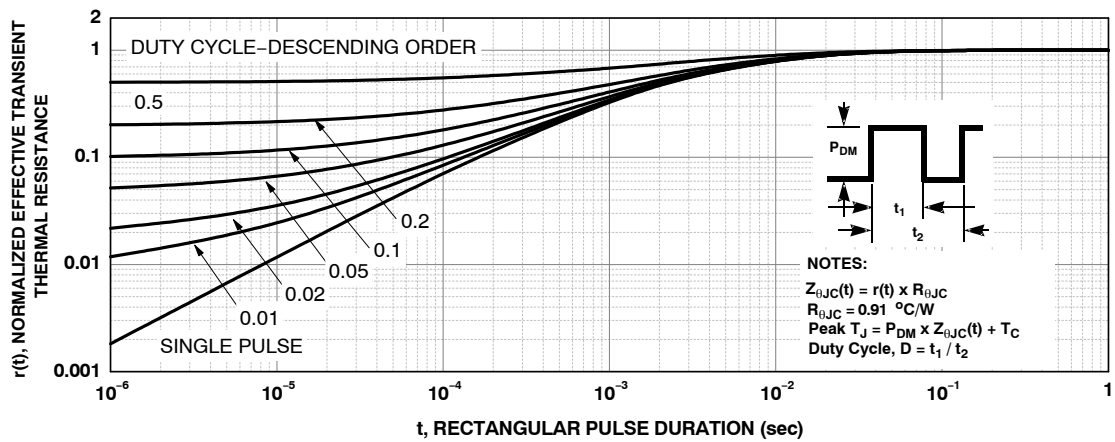


Figure 8. Junction-to-Case Transient Thermal Response Curve

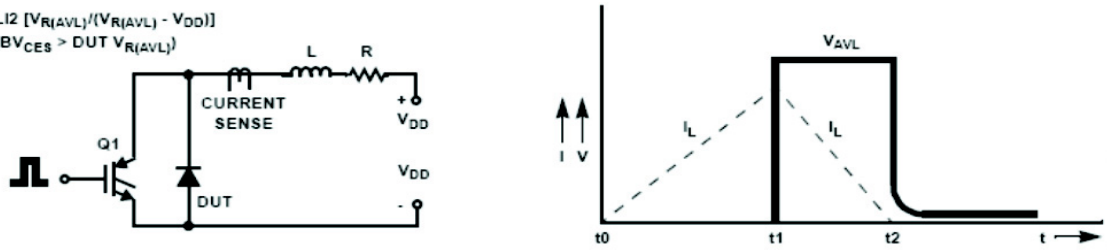
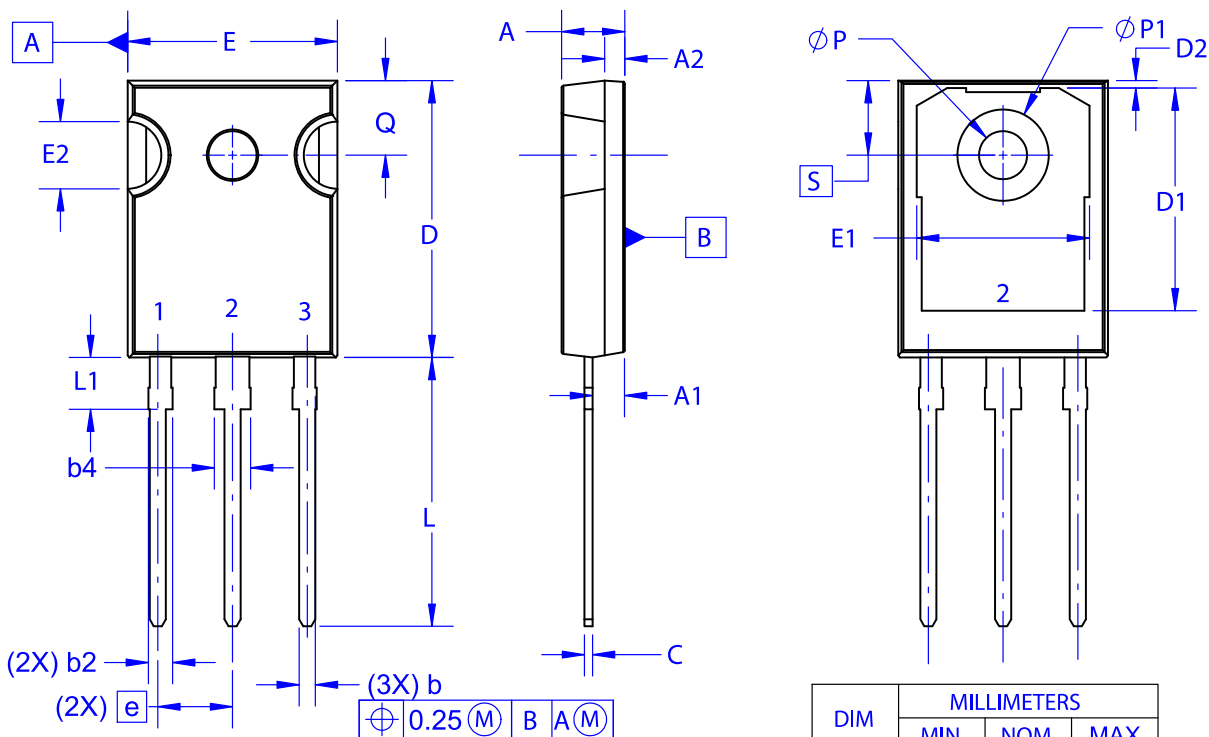
TYPICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted) $L = 0.5\text{mH}$ $R < 0.1\Omega$ $V_{DD} = 50\text{V}$ $E_{AVL} = 1/2 L I_2^2 [V_{R(AVL)} / (V_{R(AVL)} - V_{DD})]$ $Q1 = \text{IGBT } (BV_{CES} > DUT V_{R(AVL)})$ 

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

TO-247-3LD CASE 340CH ISSUE A

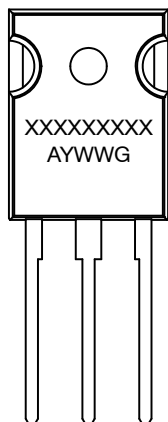
DATE 09 OCT 2019



NOTES: UNLESS OTHERWISE SPECIFIED.

- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 - 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DIM	MILLIMETERS		
	MIN	NOM	MAX
A	4.58	4.70	4.82
A1	2.29	2.475	2.66
A2	1.40	1.50	1.60
D	20.32	20.57	20.82
E	15.37	15.62	15.87
E2	4.96	5.08	5.20
e	~	5.56	~
L	19.75	20.00	20.25
L1	3.69	3.81	3.93
ØP	3.51	3.58	3.65
Q	5.34	5.46	5.58
S	5.34	5.46	5.58
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
b4	2.42	2.54	2.66
c	0.51	0.61	0.71
D1	13.08	~	~
D2	0.51	0.93	1.35
E1	12.81	~	~
ØP1	6.61	6.73	6.85

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